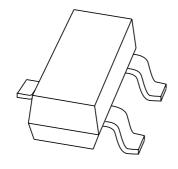
DISCRETE SEMICONDUCTORS

DATA SHEET



BC817 NPN general purpose transistor

Product specification Supersedes data of 1997 Mar 12 1999 Jun 01





NPN general purpose transistor

BC817

FEATURES

- High current (max. 500 mA)
- Low voltage (max. 45 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

NPN transistor in a SOT23 plastic package. PNP complement: BC807.

MARKING

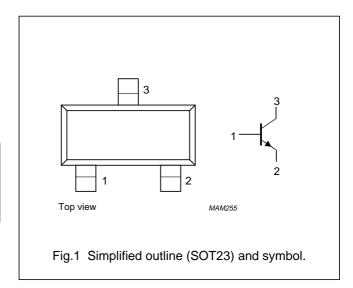
TYPE NUMBER	MARKING CODE ⁽¹⁾	TYPE NUMBER	MARKING CODE ⁽¹⁾	
BC817	6D*	BC817-25	6B*	
BC817-16	6A*	BC817-40	6C*	

Note

* = p : Made in Hong Kong.
 * = t : Made in Malaysia.

PINNING

PIN	DESCRIPTION
1	base
2	emitter
3	collector



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	_	50	V
V _{CEO}	collector-emitter voltage	open base; I _C = 10 mA	_	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)			500	mA
I _{CM}	peak collector current		_	1	А
I _{BM}	peak base current		_	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C; note 1	_	250	mW
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature		_	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

Note

1. Transistor mounted on an FR4 printed-circuit board.

NPN general purpose transistor

BC817

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

CHARACTERISTICS

 $T_j = 25$ °C unless otherwise specified.

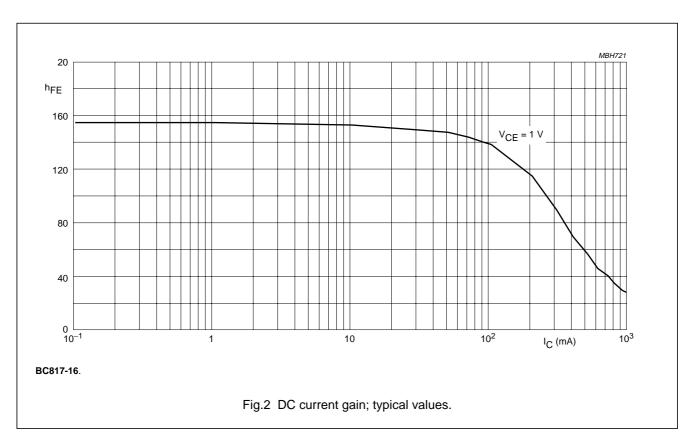
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 20 V	_	_	100	nA
		I _E = 0; V _{CB} = 20 V; T _j = 150 °C	_	_	5	μΑ
I _{EBO}	emitter cut-off current	I _C = 0; V _{EB} = 5 V	_	_	100	nA
h _{FE}	DC current gain	I _C = 100 mA; V _{CE} = 1 V; note 1;				
	BC817	see Figs 2, 3 and 4	100	_	600	
	BC817-16		100	_	250	
	BC817-25		160	_	400	
	BC817-40		250		600	
h _{FE}	DC current gain	I _C = 500 mA; V _{CE} = 1 V; note 1	40	_	_	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 500 \text{ mA}$; $I_B = 50 \text{ mA}$; note 1	_	_	700	mV
V_{BE}	base-emitter voltage	I _C = 500 mA; V _{CE} = 1 V; note 2	_	_	1.2	V
C _c	collector capacitance	$I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$;	_	5	_	pF
f _T	transition frequency	$I_C = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz};$	100	_	_	MHz

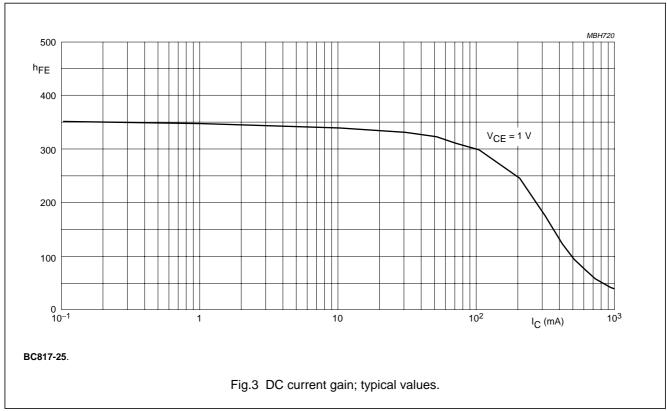
Notes

- 1. Pulse test: $t_p \le 300~\mu s;~\delta \le 0.02.$
- 2. V_{BE} decreases by approx. 2 mV/K with increasing temperature.

NPN general purpose transistor

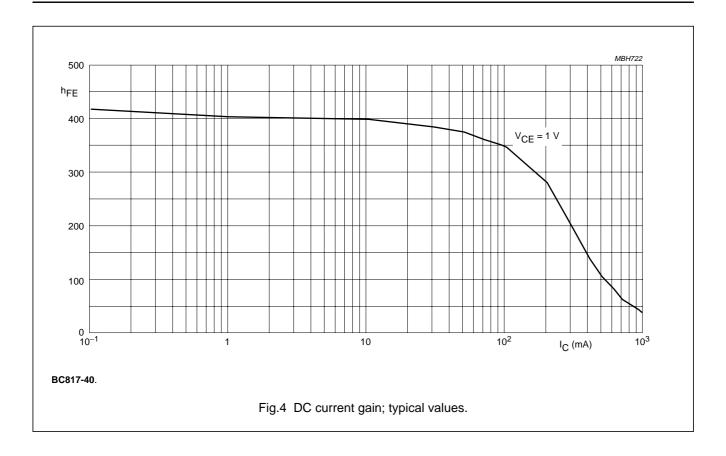
BC817





NPN general purpose transistor

BC817



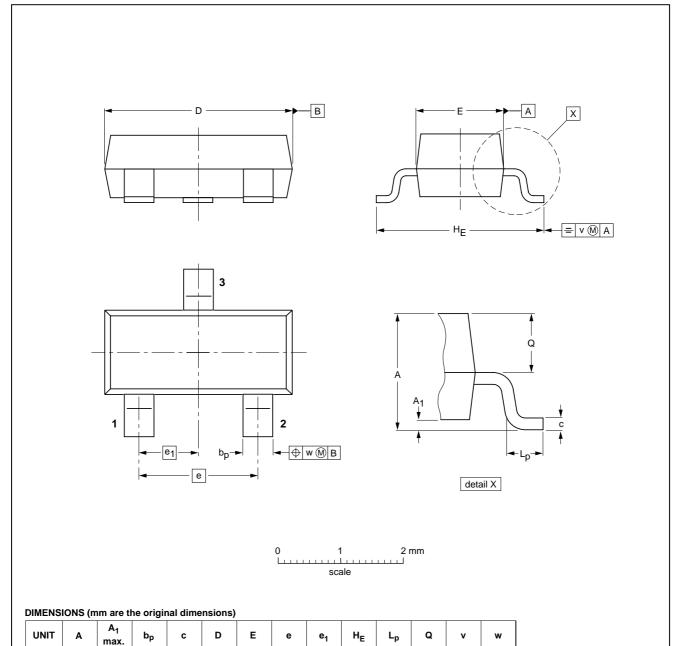
NPN general purpose transistor

BC817

PACKAGE OUTLINE

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFERENCES EUROPEAN IS			EUROPEAN ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT23						97-02-28

1.9

0.45 0.15 0.55 0.45

1999 Jun 01 6

0.48 0.38

0.1

3.0 2.8

0.15

0.09

1.1 0.9

mm

NPN general purpose transistor

BC817

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	

Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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